

ELFA artikelnr.

73-551-83 74HCT4051N logikkrets

8-CHANNEL ANALOG MULTIPLEXER/DEMULTIPLEXER

74HC/HCT4051

FEATURES

- Wide analog input voltage range: ± 5 V.
- Low "ON" resistance:
80 Ω (typ.) at $V_{CC} - V_{EE} = 4.5$ V
70 Ω (typ.) at $V_{CC} - V_{EE} = 6.0$ V
60 Ω (typ.) at $V_{CC} - V_{EE} = 9.0$ V
- Logic level translation:
to enable 5 V logic to communicate
with ± 5 V analog signals
- Typical "break before make" built in
- Output capability: non-standard
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT4051 are high-speed Si-gate CMOS devices and are pin compatible with the "4051" of the "4000B" series. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4051 are 8-channel analog multiplexers/demultiplexers with three digital select inputs (S_0 to S_2), an active LOW enable input (\bar{E}), eight independent inputs/outputs (Y_0 to Y_7) and a common input/output (Z).

With \bar{E} LOW, one of the eight switches is selected (low impedance ON-state) by S_0 to S_2 . With \bar{E} HIGH, all switches are in the high impedance OFF-state, independent of S_0 to S_2 .

V_{CC} and GND are the supply voltage pins for the digital control inputs (S_0 to S_2 , and \bar{E}). The V_{CC} to GND ranges are 2.0 to 10.0 V for HC and 4.5 to 5.5 V for HCT. The analog inputs/outputs (Y_0 to Y_7 , and Z) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. $V_{CC} - V_{EE}$ may not exceed 10.0 V.

For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND (typically ground).

| SYMBOL | PARAMETER | CONDITIONS | TYPICAL | | UNIT |
|-------------------|---|---|----------|----------|----------|
| | | | HC | HCT | |
| t_{PZH}/t_{PZL} | turn "ON" time \bar{E} to V_{OS} S_n to V_{OS} | $C_L = 15$ pF $R_L = 1$ k Ω $V_{CC} = 5$ V | 22 20 | 22 24 | ns ns |
| t_{PHZ}/t_{PLZ} | turn "OFF" time \bar{E} to V_{OS} S_n to V_{OS} | | 18 19 | 16 20 | ns ns |
| C_I | input capacitance | | 3.5 | 3.5 | pF |
| C_{PD} | power dissipation capacitance per switch | notes 1 and 2 | 25 | 25 | pF |
| C_S | max. switch capacitance independent (Y) common (Z) | | 5 | 5 | pF |
| | | | 25 | 25 | pF |

$V_{EE} = GND = 0$ V; $T_{amb} = 25$ °C; $t_r = t_f = 6$ ns

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \}$$

f_i = input frequency in MHz

f_o = output frequency in MHz

$\sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \}$ = sum of outputs

C_L = output load capacitance in pF

C_S = max. switch capacitance in pF

V_{CC} = supply voltage in V

2. For HC the condition is $V_I = GND$ to V_{CC}

For HCT the condition is $V_I = GND$ to $V_{CC} - 1.5$ V

PACKAGE OUTLINES

SEE PACKAGE INFORMATION SECTION

PIN DESCRIPTION

| PIN NO. | SYMBOL | NAME AND FUNCTION |
|----------------------------|----------------|----------------------------|
| 3 | Z | common input/output |
| 6 | \bar{E} | enable input (active LOW) |
| 7 | V_{EE} | negative supply voltage |
| 8 | GND | ground (0 V) |
| 11, 10, 9 | S_0 to S_2 | select inputs |
| 13, 14, 15, 12, 1, 5, 2, 4 | Y_0 to Y_7 | independent inputs/outputs |
| 16 | V_{CC} | positive supply voltage |

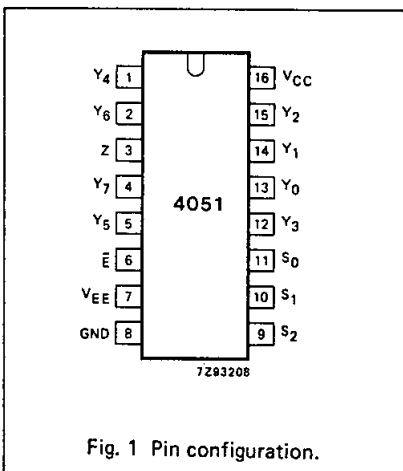


Fig. 1 Pin configuration.

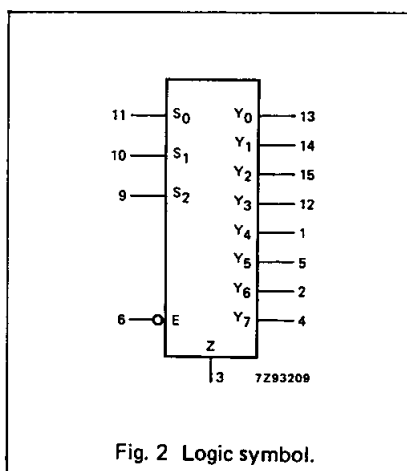


Fig. 2 Logic symbol.

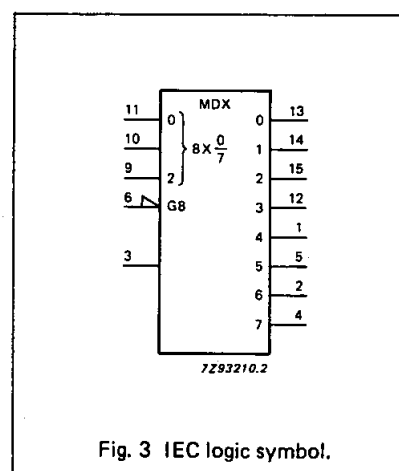
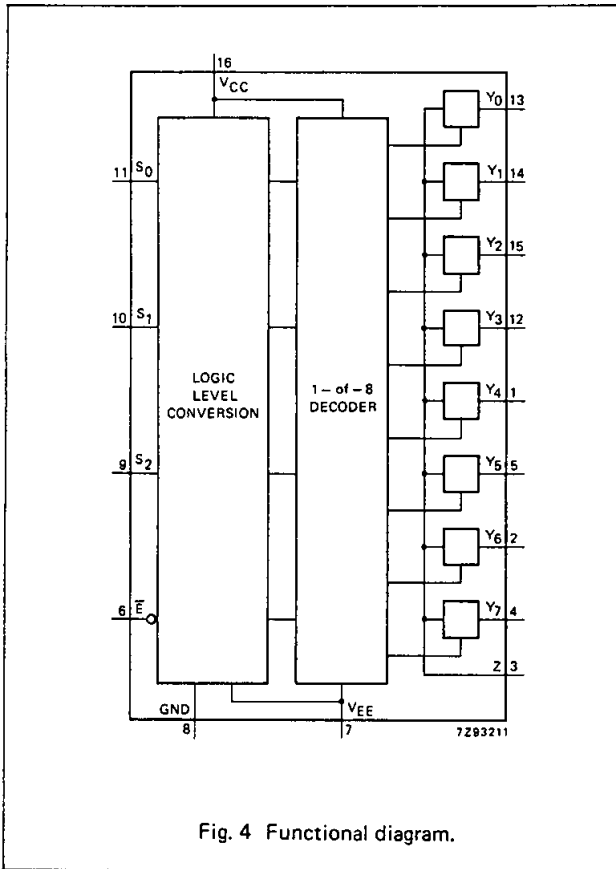


Fig. 3 IEC logic symbol.



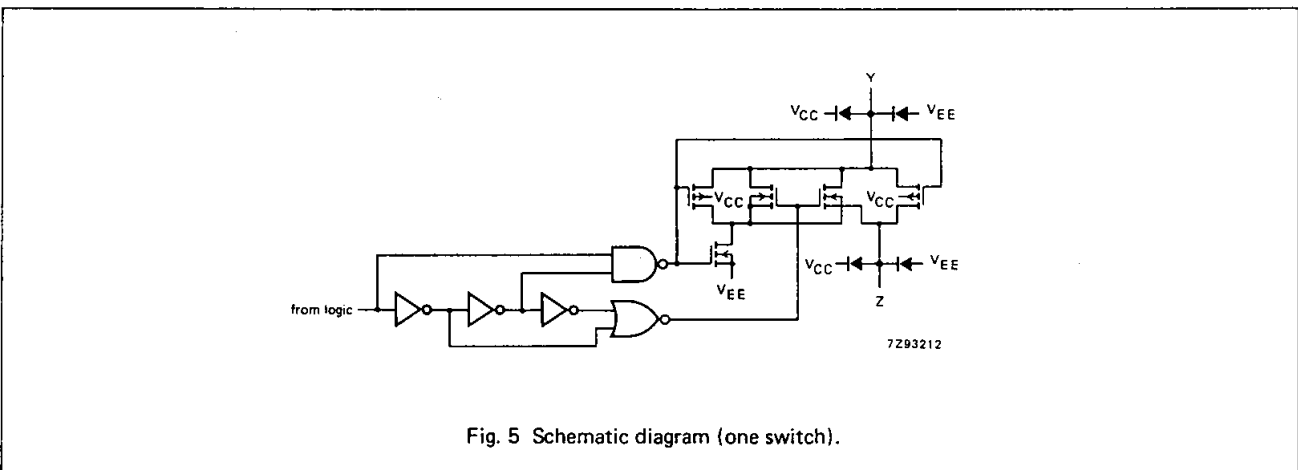
APPLICATIONS

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

FUNCTION TABLE

| INPUTS | | | | channel ON |
|-----------|----------------|----------------|----------------|--------------------|
| \bar{E} | S ₂ | S ₁ | S ₀ | |
| L | L | L | L | Y ₀ - Z |
| L | L | L | H | Y ₁ - Z |
| L | L | H | L | Y ₂ - Z |
| L | L | H | H | Y ₃ - Z |
| L | H | L | L | Y ₄ - Z |
| L | H | L | H | Y ₅ - Z |
| L | H | H | L | Y ₆ - Z |
| L | H | H | H | Y ₇ - Z |
| H | X | X | X | none |

H = HIGH voltage level
L = LOW voltage level
X = don't care




RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

 Voltages are referenced to $V_{EE} = \text{GND}$ (ground = 0 V)

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT | CONDITIONS |
|---------------------------------|--------------------------------|------|-------|------|--|
| V_{CC} | DC supply voltage | -0.5 | +11.0 | V | |
| $\pm I_{IK}$ | DC digital input diode current | | 20 | mA | for $V_I < -0.5 \text{ V}$ or $V_I > V_{CC} + 0.5 \text{ V}$ |
| $\pm I_{SK}$ | DC switch diode current | | 20 | mA | for $V_S < -0.5 \text{ V}$ or $V_S > V_{CC} + 0.5 \text{ V}$ |
| $\pm I_S$ | DC switch current | | 25 | mA | for $-0.5 \text{ V} < V_S < V_{CC} + 0.5 \text{ V}$ |
| $\pm I_{EE}$ | DC V_{EE} current | | 20 | mA | |
| $\pm I_{CC}$; $\pm I_{GND}$ | DC V_{CC} or GND current | | 50 | mA | |
| T_{stg} | storage temperature range | -65 | +150 | °C | |
| P_{tot} | power dissipation per package | | | | for temperature range: -40 to +125 °C 74HC/HCT |
| | plastic DIL | | 750 | mW | above +70 °C: derate linearly with 12 mW/K |
| | plastic mini-pack (SO) | | 500 | mW | above +70 °C: derate linearly with 8 mW/K |
| P_S | power dissipation per switch | | 100 | mW | |

Note to ratings

To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminals Y_n , the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Y_n . In this case there is no limit for the voltage drop across the switch, but the voltages at Y_n and Z may not exceed V_{CC} or V_{EE} .

RECOMMENDED OPERATING CONDITIONS

| SYMBOL | PARAMETER | 74HC | | | 74HCT | | | UNIT | CONDITIONS |
|------------|---------------------------------------|----------|------|---------------------------|----------|------|----------|------|---|
| | | min. | typ. | max. | min. | typ. | max. | | |
| V_{CC} | DC supply voltage $V_{CC}-\text{GND}$ | 2.0 | 5.0 | 10.0 | 4.5 | 5.0 | 5.5 | V | see Figs 6 and 7 |
| V_{CC} | DC supply voltage $V_{CC}-V_{EE}$ | 2.0 | 5.0 | 10.0 | 2.0 | 5.0 | 10.0 | V | see Figs 6 and 7 |
| V_I | DC input voltage range | GND | | V_{CC} | GND | | V_{CC} | V | |
| V_S | DC switch voltage range | V_{EE} | | V_{CC} | V_{EE} | | V_{CC} | V | |
| T_{amb} | operating ambient temperature range | -40 | | +85 | -40 | | +85 | °C | see DC and AC CHARACTERISTICS |
| T_{amb} | operating ambient temperature range | -40 | | +125 | -40 | | +125 | °C | |
| t_r, t_f | input rise and fall times | | 6.0 | 1000 500 400 250 | | 6.0 | 500 | ns | $V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$ $V_{CC} = 10.0 \text{ V}$ |

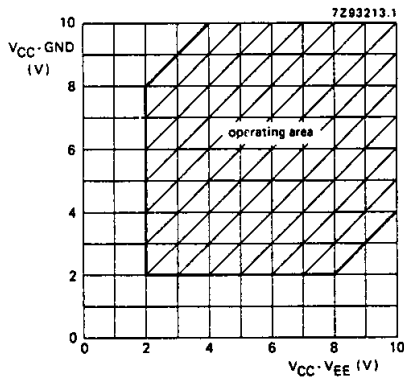


Fig. 6 Guaranteed operating area as a function of the supply voltages for 74HC4051.

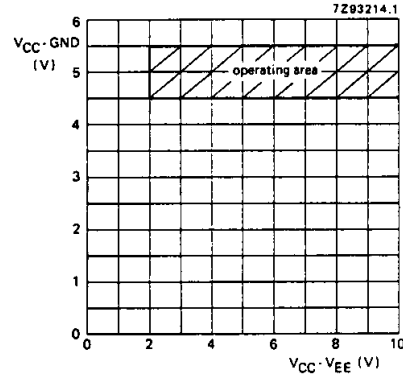


Fig. 7 Guaranteed operating area as a function of the supply voltages for 74HCT4051.

DC CHARACTERISTICS FOR 74HC/HCT

For 74HC: $V_{CC} - GND$ or $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$ and 9.0 V

For 74HCT: $V_{CC} - GND = 4.5$ and 5.5 V; $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$ and 9.0 V

| SYMBOL | PARAMETER | T_{amb} (°C) | | | | | | UNIT | TEST CONDITIONS | | | | | |
|-----------------|--|----------------|------|------|------------|------|-------------|------|-----------------|---------------|------------------|----------|----------------------------|----------------------------|
| | | 74HC/HCT | | | | | | | V_{CC} V | V_{EE} V | I_S μA | V_{is} | V_I | |
| | | +25 | | | -40 to +85 | | -40 to +125 | | | | | | | |
| | | min. | typ. | max. | min. | max. | min. | | | | | | | max. |
| R_{ON} | ON resistance (peak) | | — | — | | — | | — | Ω | 2.0 | 0 | 100 | V_{CC} to V_{EE} | V_{IH} or V_{IL} |
| | | | 100 | 180 | | 225 | | 270 | Ω | 4.5 | 0 | 1000 | | |
| | | | 90 | 160 | | 200 | | 240 | Ω | 6.0 | 0 | 1000 | | |
| | | | 70 | 130 | | 165 | | 195 | Ω | 4.5 | -4.5 | 1000 | | |
| R_{ON} | ON resistance (rail) | | 150 | — | | — | | — | Ω | 2.0 | 0 | 100 | V_{EE} | V_{IH} or V_{IL} |
| | | | 80 | 140 | | 175 | | 210 | Ω | 4.5 | 0 | 1000 | | |
| | | | 70 | 120 | | 150 | | 180 | Ω | 6.0 | 0 | 1000 | | |
| | | | 60 | 105 | | 130 | | 160 | Ω | 4.5 | -4.5 | 1000 | | |
| R_{ON} | ON resistance (rail) | | 150 | — | | — | | — | Ω | 2.0 | 0 | 100 | V_{CC} | V_{IH} or V_{IL} |
| | | | 90 | 160 | | 200 | | 240 | Ω | 4.5 | 0 | 1000 | | |
| | | | 80 | 140 | | 175 | | 210 | Ω | 6.0 | 0 | 1000 | | |
| | | | 65 | 120 | | 150 | | 180 | Ω | 4.5 | -4.5 | 1000 | | |
| ΔR_{ON} | maximum ΔON resistance between any two channels | | — | | | | | | Ω | 2.0 | 0 | | V_{CC} to V_{EE} | V_{IH} or V_{IL} |
| | | | 9 | | | | | | Ω | 4.5 | 0 | | | |
| | | | 8 | | | | | | Ω | 6.0 | 0 | | | |
| | | | 6 | | | | | | Ω | 4.5 | -4.5 | | | |

Notes to DC characteristics

- At supply voltages ($V_{CC} - V_{EE}$) approaching 2.0 V the analog switch ON-resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
- For test circuit measuring R_{ON} see Fig. 8.


DC CHARACTERISTICS FOR 74HC

Voltages are referenced to GND (ground = 0 V)

| SYMBOL | PARAMETER | T _{amb} (°C) | | | | | | | | UNIT | TEST CONDITIONS | | | |
|-----------------|--|---------------------------|--------------------------|---------------------------|---------------------------|---------------------------|---------------------------|---------------------------|----|--------------------------|----------------------|--|--|-------|
| | | 74HC | | | | | | | | | V _{CC} V | V _{EE} V | V _I | OTHER |
| | | +25 | | | -40 to +85 | | -40 to +125 | | | | | | | |
| | | min. | typ. | max. | min. | max. | min. | max. | | | | | | |
| V _{IH} | HIGH level input voltage | 1.5 3.15 4.2 6.3 | 1.2 2.4 3.2 4.7 | | 1.5 3.15 4.2 6.3 | | 1.5 3.15 4.2 6.3 | | V | 2.0 4.5 6.0 9.0 | | | | |
| V _{IL} | LOW level input voltage | | 0.8 2.1 2.8 4.3 | 0.5 1.35 1.8 2.7 | | 0.5 1.35 1.8 2.7 | | 0.5 1.35 1.8 2.7 | V | 2.0 4.5 6.0 9.0 | | | | |
| ±I _I | input leakage current | | | 0.1 0.2 | | 1.0 2.0 | | 1.0 2.0 | µA | 6.0 10.0 | 0 0 | V _{CC} or GND | | |
| ±I _S | analog switch OFF-state current per channel | | | 0.1 | | 1.0 | | 1.0 | µA | 10.0 | 0 | V _{IH} or V _{IL} | V _S = V _{CC} - V _{EE} (see Fig. 10) | |
| ±I _S | analog switch OFF-state current all channels | | | 0.4 | | 4.0 | | 4.0 | µA | 10.0 | 0 | V _{IH} or V _{IL} | V _S = V _{CC} - V _{EE} (see Fig. 10) | |
| ±I _S | analog switch ON-state current | | | 0.4 | | 4.0 | | 4.0 | µA | 10.0 | 0 | V _{IH} or V _{IL} | V _S = V _{CC} - V _{EE} (see Fig. 11) | |
| I _{CC} | quiescent supply current | | | 8.0 16.0 | | 80.0 160.0 | | 160.0 320.0 | µA | 6.0 10.0 | 0 0 | V _{CC} or GND | V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE} | |

AC CHARACTERISTICS FOR 74HC

 GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

| SYMBOL | PARAMETER | T_{amb} (°C) | | | | | | UNIT | TEST CONDITIONS | | | |
|-------------------------|---|----------------|----------------------|-----------------------|------------|-----------------------|-------------|------------------------|-----------------|--------------------------|---------------------|--|
| | | 74HC | | | | | | | V_{CC} V | V_{EE} V | OTHER | |
| | | +25 | | | -40 to +85 | | -40 to +125 | | | | | |
| | | min. | typ. | max. | min. | max. | min. | | | | | max. |
| $t_{PHL}/$ t_{PLH} | propagation delay V_{is} to V_{os} | | 14 5 4 4 | 60 12 10 8 | | 75 15 13 10 | | 90 18 15 12 | ns | 2.0 4.5 6.0 4.5 | 0 0 0 -4.5 | $R_L = \infty$; $C_L = 50$ pF (see Fig. 17) |
| $t_{PZH}/$ t_{PZL} | turn "ON" time \bar{E} to V_{os} | | 72 29 21 18 | 345 69 59 51 | | 430 86 73 64 | | 520 104 88 77 | ns | 2.0 4.5 6.0 4.5 | 0 0 0 -4.5 | $R_L = 1$ k Ω ; $C_L = 50$ pF (see Figs 18, 19 and 20) |
| $t_{PHZ}/$ t_{PZL} | turn "ON" time S_n to V_{os} | | 66 28 19 16 | 345 69 59 51 | | 430 86 73 64 | | 520 104 88 77 | ns | 2.0 4.5 6.0 4.5 | 0 0 0 -4.5 | $R_L = 1$ k Ω ; $C_L = 50$ pF (see Figs 18, 19 and 20) |
| $t_{PHZ}/$ t_{PLZ} | turn "OFF" time \bar{E} to V_{os} | | 58 31 17 18 | 290 58 49 42 | | 365 73 62 53 | | 435 87 74 72 | ns | 2.0 4.5 6.0 4.5 | 0 0 0 -4.5 | $R_L = 1$ k Ω ; $C_L = 50$ pF (see Figs 18, 19 and 20) |
| $t_{PHZ}/$ t_{PLZ} | turn "OFF" time S_n to V_{os} | | 61 25 18 18 | 290 58 49 42 | | 365 73 62 53 | | 435 87 74 72 | ns | 2.0 4.5 6.0 4.5 | 0 0 0 -4.5 | $R_L = 1$ k Ω ; $C_L = 50$ pF (see Figs 18, 19 and 20) |


DC CHARACTERISTICS FOR 74HCT

Voltages are referenced to GND (ground = 0)

| SYMBOL | PARAMETER | T _{amb} (°C) | | | | | | UNIT | TEST CONDITIONS | | | | |
|------------------|---|-----------------------|------|-------------|------------|---------------|-------------|----------------|----------------------|----------------------|----------------|--|--|
| | | 74HCT | | | | | | | V _{CC} V | V _{EE} V | V _I | OTHER | |
| | | +25 | | | -40 to +85 | | -40 to +125 | | | | | | |
| | | min. | typ. | max. | min. | max. | min. | | | | | | max. |
| V _{IH} | HIGH level input voltage | 2.0 | 1.6 | | 2.0 | | 2.0 | | V | 4.5 to 5.5 | | | |
| V _{IL} | LOW level input voltage | | 1.2 | 0.8 | | 0.8 | | 0.8 | V | 4.5 to 5.5 | | | |
| ±I _I | input leakage current | | | 0.1 | | 1.0 | | 1.0 | μA | 5.5 | 0 | V _{CC} or GND | |
| ±I _S | analog switch OFF-state current per channel | | | 0.1 | | 1.0 | | 1.0 | μA | 10.0 | 0 | V _{IH} or V _{IL} | V _S = V _{CC} - V _{EE} (see Fig. 10) |
| ±I _S | analog switch OFF-state current all channels | | | 0.4 | | 4.0 | | 4.0 | μA | 10.0 | 0 | V _{IH} or V _{IL} | V _S = V _{CC} - V _{EE} (see Fig. 10) |
| ±I _S | analog switch ON-state current | | | 0.4 | | 4.0 | | 4.0 | μA | 10.0 | 0 | V _{IH} or V _{IL} | V _S = V _{CC} - V _{EE} (see Fig. 11) |
| I _{CC} | quiescent supply current | | | 8.0 16.0 | | 80.0 160.0 | | 160.0 320.0 | μA | 5.5 5.0 | 0 -5.0 | V _{CC} or GND | V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE} |
| ΔI _{CC} | additional quiescent supply current per input pin for unit load coefficient is 1 (note 1) | | 100 | 360 | | 450 | | 490 | μA | 4.5 to 5.5 | 0 | V _{CC} -2.1V | other inputs at V _{CC} or GND |

Note to HCT types

 1. The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given here.

 To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

| INPUT | UNIT LOAD COEFFICIENT |
|----------------|-----------------------|
| S _n | 0.50 |
| E | 0.50 |

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

| SYMBOL | PARAMETER | T_{amb} (°C) | | | | | | UNIT | TEST CONDITIONS | | |
|-------------------|---|----------------|----------|------|------------|------|-------------|------|-----------------|---------------|--|
| | | 74HCT | | | | | | | V_{CC} V | V_{EE} V | OTHER |
| | | +25 | | | -40 to +85 | | -40 to +125 | | | | |
| | | min. | typ. | max. | min. | max. | min. | | max. | | |
| t_{PHL}/t_{PLH} | propagation delay V_{is} to V_{Os} | 5 4 | 12 8 | | 15 10 | | 18 12 | ns | 4.5 4.5 | 0 -4.5 | $R_L = \infty$; $C_L = 50$ pF (see Fig. 17) |
| t_{PZH}/t_{PZL} | turn "ON" time \bar{E} to V_{Os} | 26 16 | 55 39 | | 69 49 | | 83 59 | ns | 4.5 4.5 | 0 -4.5 | $R_L = 1$ k Ω ; $C_L = 50$ pF (see Figs 18, 19 and 20) |
| t_{PZH}/t_{PZL} | turn "ON" time S_n to V_{Os} | 28 16 | 55 39 | | 69 49 | | 83 59 | ns | 4.5 4.5 | 0 -4.5 | $R_L = 1$ k Ω ; $C_L = 50$ pF (see Figs 18, 19 and 20) |
| t_{PHZ}/t_{PLZ} | turn "OFF" time \bar{E} to V_{Os} | 19 16 | 45 32 | | 56 40 | | 68 48 | ns | 4.5 4.5 | 0 -4.5 | $R_L = 1$ k Ω ; $C_L = 50$ pF (see Figs 18, 19 and 20) |
| t_{PHZ}/t_{PLZ} | turn "OFF" time S_n to V_{Os} | 23 16 | 45 32 | | 56 40 | | 68 48 | ns | 4.5 4.5 | 0 -4.5 | $R_L = 1$ k Ω ; $C_L = 50$ pF (see Figs 18, 19 and 20) |

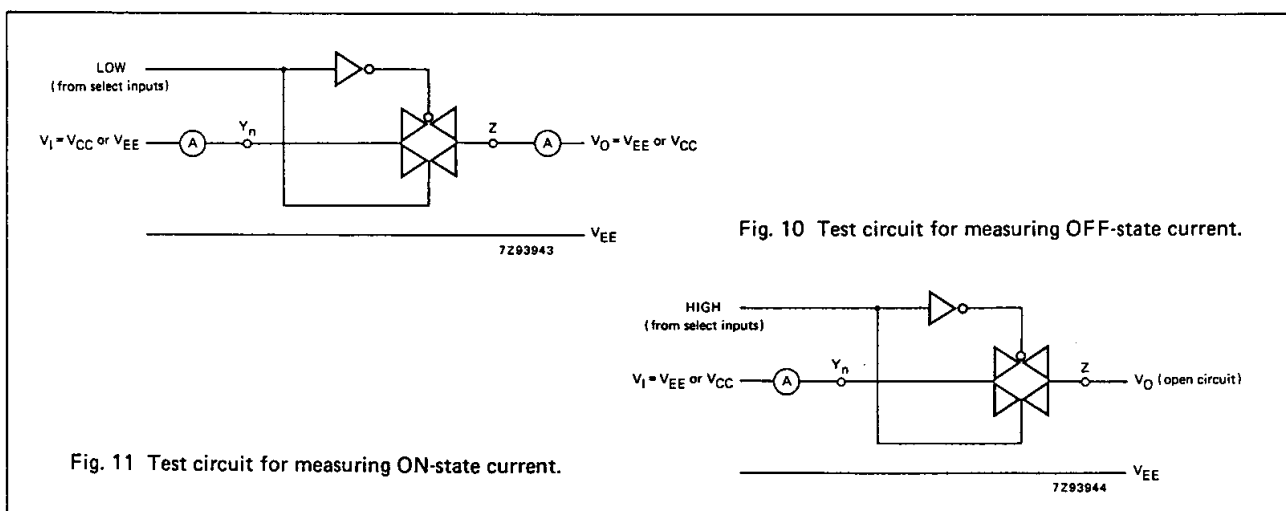
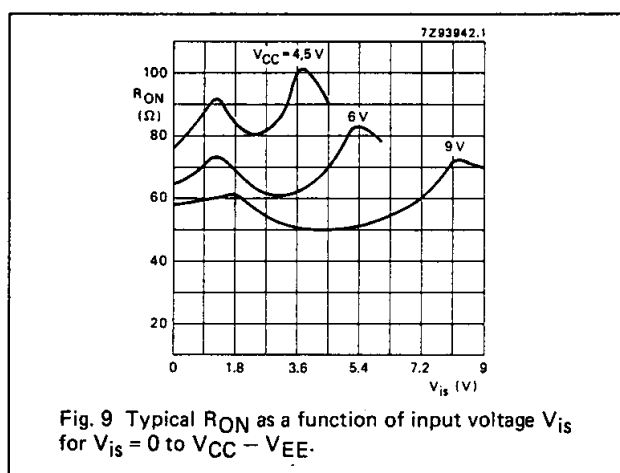
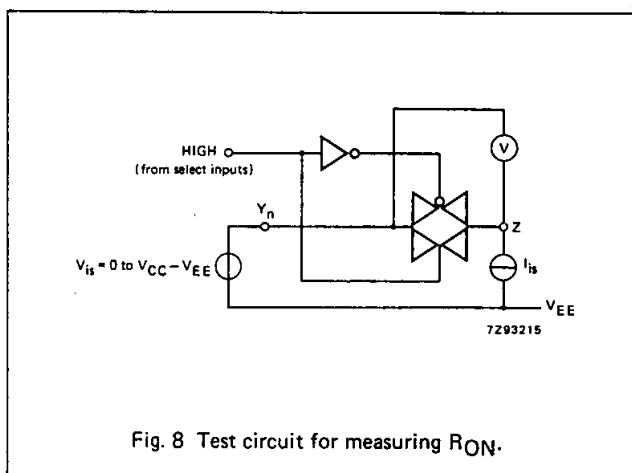
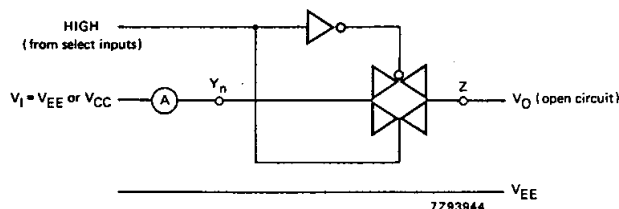


Fig. 11 Test circuit for measuring ON-state current.



ADDITIONAL AC CHARACTERISTICS FOR 74HC/HCT

Recommended conditions and typical values

GND = 0 V; $T_{amb} = 25\text{ }^{\circ}\text{C}$

| SYMBOL | PARAMETER | typ. | UNIT | V_{CC} V | V_{EE} V | $V_{is(p-p)}$ V | CONDITIONS |
|-------------|---|--------------|------------|---------------|---------------|--------------------|--|
| | sine-wave distortion $f = 1\text{ kHz}$ | 0.04 0.02 | % % | 2.25 4.5 | -2.25 -4.5 | 4.0 8.0 | $R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$ (see Fig. 14) |
| | sine-wave distortion $f = 10\text{ kHz}$ | 0.12 0.06 | % % | 2.25 4.5 | -2.25 -4.5 | 4.0 8.0 | $R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$ (see Fig. 14) |
| | switch "OFF" signal feed-through | -50 -50 | dB dB | 2.25 4.5 | -2.25 -4.5 | note 1 | $R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$ (see Figs 12 and 15) |
| $V_{(p-p)}$ | crosstalk voltage between control and any switch (peak-to-peak value) | 110 220 | mV mV | 4.5 4.5 | 0 -4.5 | | $R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$; $f = 1\text{ MHz}$ (\bar{E} or S_n , square-wave between V_{CC} and GND, $t_r = t_f = 6\text{ ns}$) (see Fig. 16) |
| f_{max} | minimum frequency response (-3dB) | 170 180 | MHz MHz | 2.25 4.5 | -2.25 -4.5 | note 2 | $R_L = 50\text{ }\Omega$; $C_L = 10\text{ pF}$ (see Figs 13 and 14) |
| C_S | maximum switch capacitance independent (Y) common (Z) | 5 25 | pF pF | | | | |

Notes to AC characteristics

General note

V_{is} is the input voltage at a Y_n or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Y_n or Z terminal, whichever is assigned as an output.

Notes

1. Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).
2. Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).

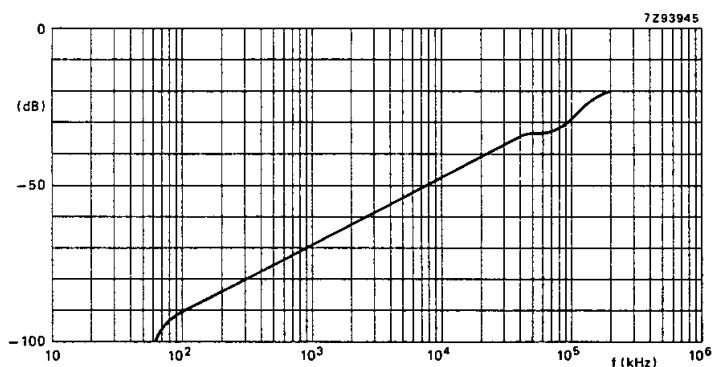
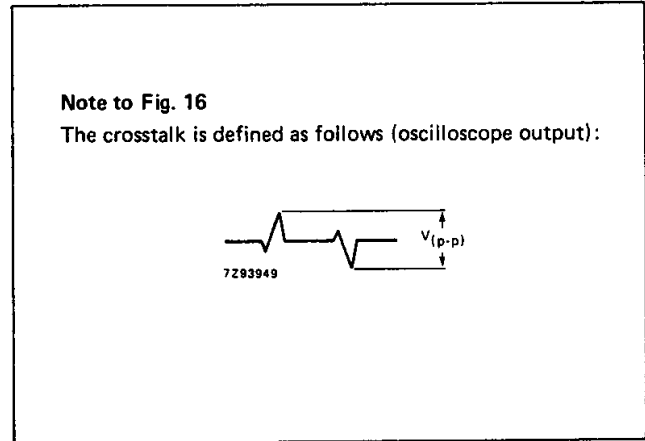
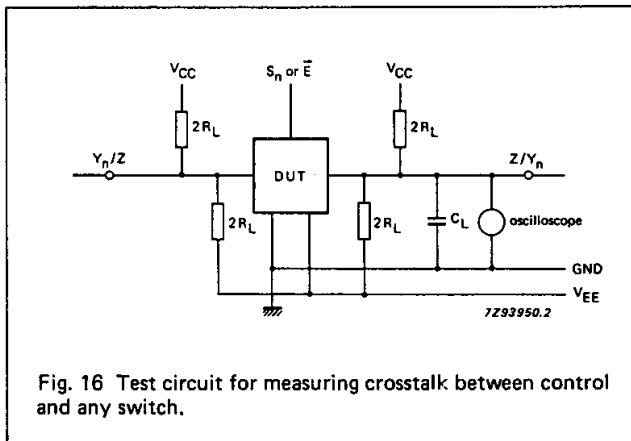
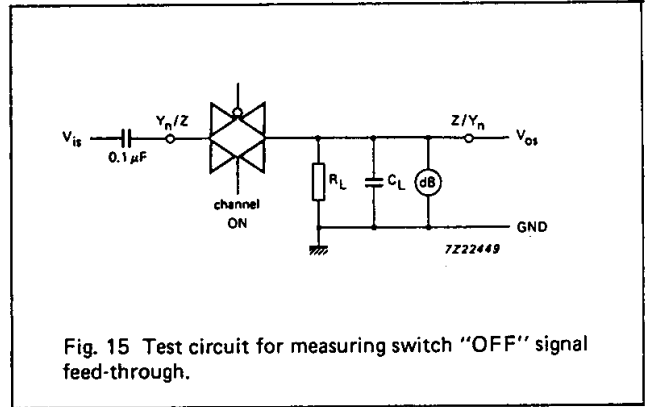
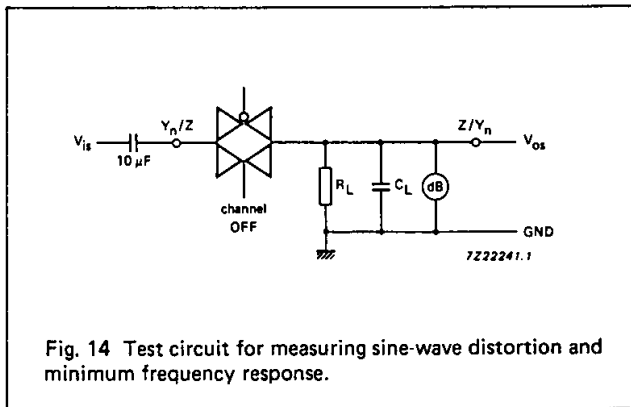
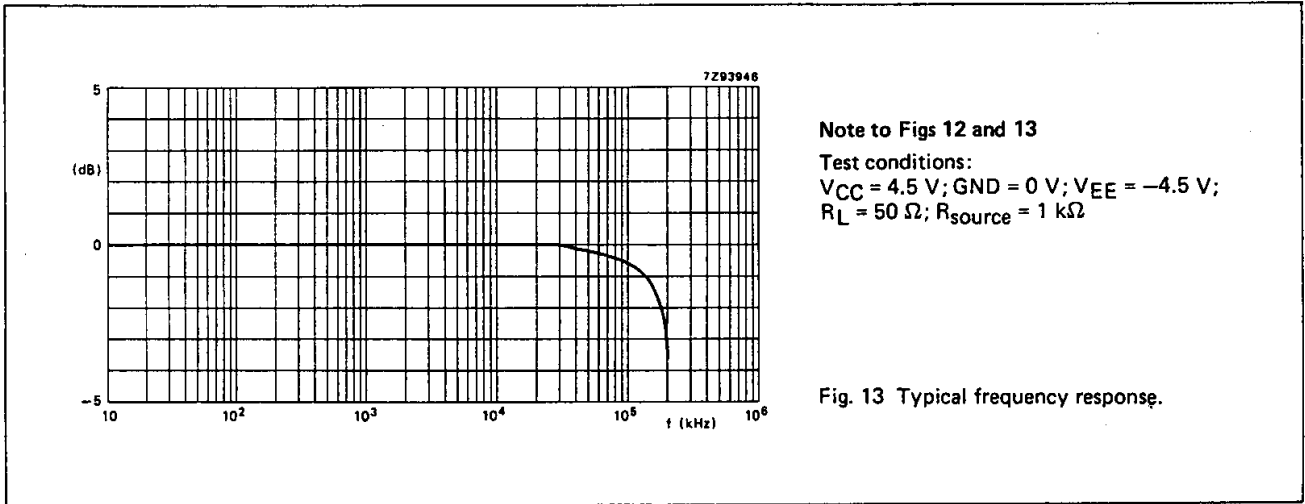
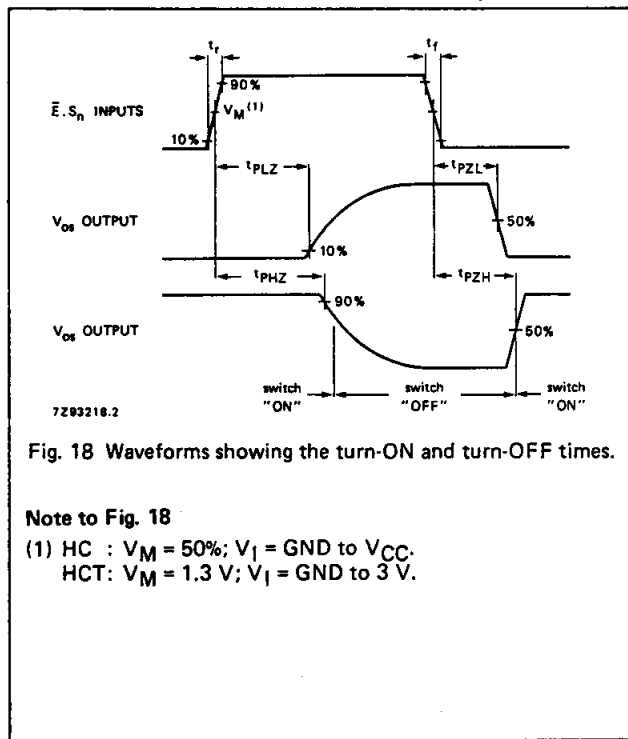
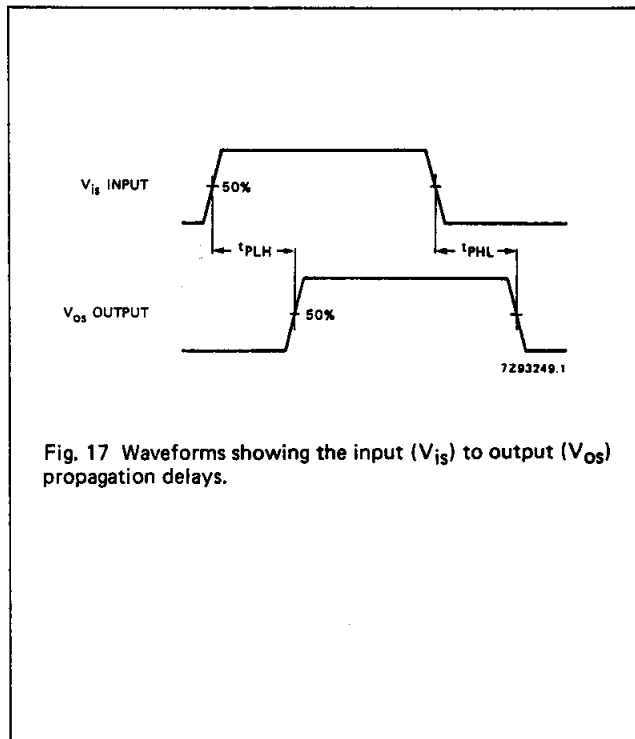


Fig. 12 Typical switch "OFF" signal feed-through as a function of frequency.



AC WAVEFORMS



TEST CIRCUIT AND WAVEFORMS

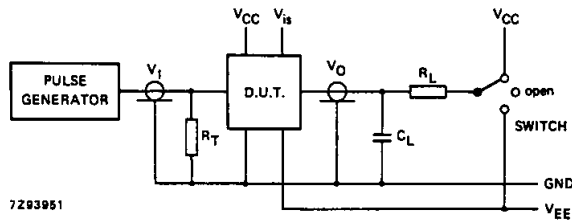


Fig. 19 Test circuit for measuring AC performance.

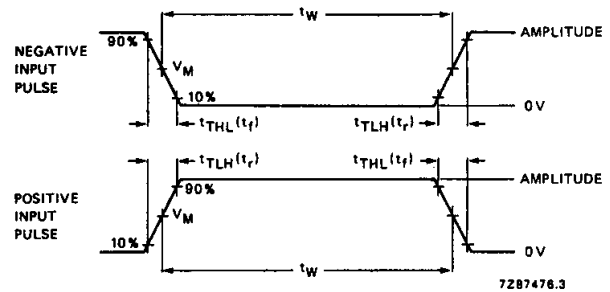


Fig. 20 Input pulse definitions.

Conditions

| TEST | SWITCH | V _{is} |
|------------------|-----------------|-----------------------|
| t _{PZH} | V _{EE} | V _{CC} |
| t _{PZL} | V _{CC} | V _{EE} |
| t _{PHZ} | V _{EE} | V _{CC} |
| t _{PLZ} | V _{CC} | V _{EE} |
| others | open | V _{EE} pulse |

| FAMILY | AMPLITUDE | V _M | t _r ; t _f | |
|--------|-----------------|----------------|---------------------------------|-------|
| | | | f _{max} ; PULSE WIDTH | OTHER |
| 74HC | V _{CC} | 50% | < 2 ns | 6 ns |
| 74HCT | 3.0 V | 1.3 V | < 2 ns | 6 ns |

Definitions for Figs 19 and 20:

- C_L = load capacitance including jig and probe capacitance (see AC CHARACTERISTICS for values).
- R_T = termination resistance should be equal to the output impedance Z_O of the pulse generator.
- t_r = t_f = 6 ns; when measuring f_{max}, there is no constraint to t_r, t_f with 50% duty factor.